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PATENT APPLICATION  
Docket No. 9898-302  
Client No. SS-18242-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: You-Seung JIN and Jong-Hyon AHN  
Serial No. 10/676,304 Examiner: Abraham, Fetsum  
Filed: September 30, 2003 Art Unit: 2826  
Confirmation No. 8176  
For: MOSFET AND METHOD OF FABRICATING THE SAME

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

- ☐ under 37 CFR 1.97 (b); or  
(Within three months of filing national application; or date of entry of International application;  
or before mailing date of first office action on the merits; or before the mailing of a first Office  
Action after the filing of a request for continued examination under §1.114; whichever occurs  
last)  
☒ under 37 CFR 1.97 (c) together with either a:  
☒ Statement under 37 CFR 1.97 (e), or  
☐ a \$180 fee under 37 CFR 1.17 (p); or  
(After mailing of first Office Action, but prior to Notice of Allowance or Final Office Action)

☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with  
copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s)  
may be material to the examination of this application and for which there may be a duty to disclose in accordance  
with 37 CFR 1.56.

- ☒ A copy of the Limited Recognition Under 37 CFR § 10.9(b).

It is requested that the information disclosed herein be made of record in this application.

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703. A  
duplicate copy of this sheet is enclosed.

Customer No. 20575

Respectfully submitted,  
MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee  
Reg. No.

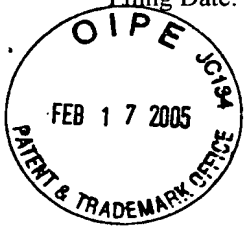
MARGER JOHNSON & McCOLLOM, P.C.  
1030 SW Morrison Street  
Portland, OR 97205  
503-222-3613

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Patents, P.O. Box 1450, Alexandria, VA 22313-  
1450  
Date: February 15, 2005

  
Li Mei Vermilya

PATENT APPLICATION

Atty. Docket No.: 9898-302 Serial No. 10/676,304  
Applicant: You-Seung JIN and Jong-Hyon AHN  
Filing Date: September 30, 2003 Group: 2826



INFORMATION DISCLOSURE CITATION  
FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
_____	_____	2002/0195660	Dec. 26, 02	Lee		

FOREIGN PATENT DOCUMENTS

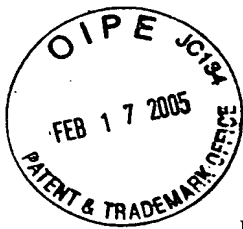
<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
_____	_____	1998-040751	Aug. 17, 98	Korea	Jun HWANG
_____	_____	2002-0091886	Dec. 11, 02	Korea	Han-Seop CHA

OTHER DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
_____	_____	English language abstract of Korean Publication No. 1998-040751
_____	_____	English language abstract of Korean Publication No. 2002-0091886

Examiner: \_\_\_\_\_

Date Considered: \_\_\_\_\_



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STATEMENT ON FILING INFORMATION DISCLOSURE STATEMENT  
(37 CFR 1.97(e))

I, Hosoon Lee, the person signing below state that:

each item of information contained in the Information Disclosure Statement submitted herewith was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Statement

no information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application and, to the knowledge of the person signing this Statement after making reasonable inquiry, was known to any individual designated in § 1.56(c) more than three months prior to the filing of the Statement.

Applicant respectfully requests consideration of the accompanying Information Disclosure Statement.

The person making this Statement is the attorney who signs below on the basis of the information in the attorney's file.

Respectfully submitted,  
MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee, Limited Recognition Under 37 CFR § 10.9(b)

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1030 SW Morrison Street  
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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450  
Date: February 15, 2005

Li Mei Vermilya